

Vishay General Semiconductor

RoHS

## **Dual Common Cathode High Voltage Schottky Rectifier**

Low Leakage Current 5.0 µA





PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	2 x 5 A				
$V_{RRM}$	150 V				
I <sub>FSM</sub> 160 A					
V <sub>F</sub>	0.72 V				
T <sub>J</sub> max.	175 °C				
Package	TO-220AB, ITO-220AB, TO-262AA				
Diode variations	Common cathode				

### **FEATURES**

- Power pack
- · Guardring for overvoltage protection
- Lower power losses, high efficiency
- Low forward voltage drop
- High forward surge capability
- High frequency operation
- Solder dip 275 °C max.10 s, per JESD 22-B106
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>

### TYPICAL APPLICATIONS

For use in high frequency inverters, freewheeling, and polarity protection application.

### **MECHANICAL DATA**

Case: TO-220AB, ITO-220AB, TO-262AA

Molding compound meets UL 94 V-0 flammability rating

Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	VALUE	UNIT			
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	150	V			
Working peak reverse voltage	V <sub>RWM</sub>	150	V			
Maximum DC blocking voltage	V <sub>DC</sub>	150	V			
Maximum average forward rectified aurrent (fig. 1)	I	10	А			
Maximum average forward rectified current (fig.1) per diode	I <sub>F(AV)</sub>	5	A			
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I <sub>FSM</sub>	160	А			
Peak repetitive reverse current per diode at t <sub>p</sub> = 2 µs, 1 kHz	I <sub>RRM</sub>	1.0	А			
Peak non-repetitive reverse surge energy per diode (8/20 waveform)	E <sub>RSM</sub>	10	mJ			
Non-repetitve avalanche energy per diode at 25 °C, $I_{AS}$ = 1.5 A, L = 10 mH	E <sub>AS</sub>	11.25	mJ			
Voltage rate of change (rated V <sub>R</sub> )	dV/dt	10 000	V/µs			
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	-65 to +175	°C			
Isolation voltage (ITO-220AB only) from terminals to heatsink t = 1 min	V <sub>AC</sub>	1500	V			

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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	TEST CONDITIONS		TYP.	MAX.	UNIT	
Maximum instantaneous forward voltage per diode	V <sub>F</sub> <sup>(1)</sup>	I <sub>F</sub> = 5 A	T <sub>J</sub> = 25 °C	-	0.88	V	
		I <sub>F</sub> = 5 A	T <sub>J</sub> = 125 °C	-	0.72		
		I <sub>F</sub> = 10 A	T <sub>J</sub> = 25 °C	-	0.96		
		I <sub>F</sub> = 10 A	T <sub>J</sub> = 125 °C	-	0.80		
Maximum reverse current per diode at working peak reverse voltage	I <sub>R</sub> <sup>(2)</sup>		T <sub>J</sub> = 25 °C	-	5.0	μΑ	
			T <sub>J</sub> = 125 °C	-	1.0	mA	

#### Notes

<sup>(2)</sup> Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	MBR	MBRF	MBRB	UNIT	
Typical thermal resistance per diode	$R_{ heta JC}$	2.4	4.5	2.4	°C/W	

ORDERING INFORMATION (Example)								
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
TO-220AB	MBR10H150CT-E3/45	2.06	45	50/tube	Tube			
ITO-220AB	MBRF10H150CT-E3/45	2.20	45	50/tube	Tube			
TO-262AA	SB10H150CT-1E3/45	1.58	45	50/tube	Tube			

### RATINGS AND CHARACTERISTICS CURVES (T<sub>A</sub> = 25 °C unless otherwise noted)

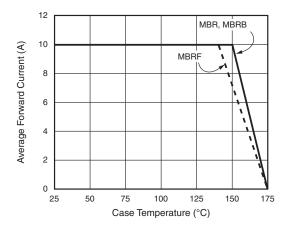


Fig. 1 - Forward Derating Curve (Total)

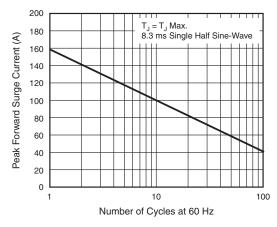


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

<sup>(1)</sup> Pulse test: 300 μs pulse width, 1 % duty cycle



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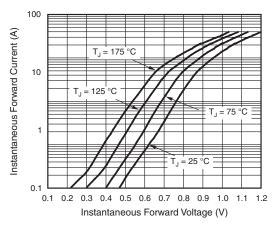


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

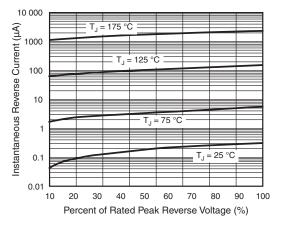


Fig. 4 - Typical Reverse Characteristics Per Diode

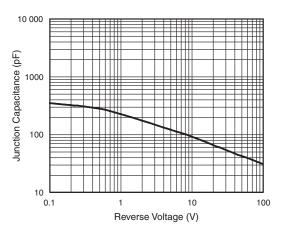


Fig. 5 - Typical Junction Capacitance Per Diode

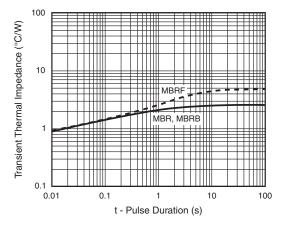


Fig. 6 - Typical Transient Thermal Impedance Per Diode



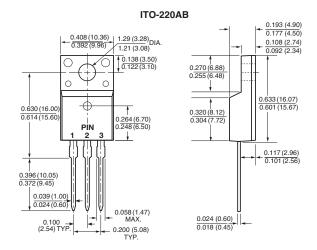
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### PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

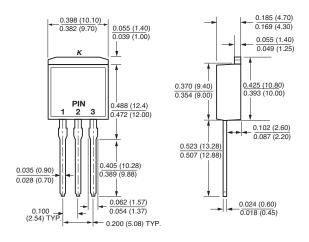
0.024 (0.60) 0.018 (0.45)

### TO-220AB 0.398 (10.10) 0.382 (9.70) 0.185 (4.70) 0.169 (4.30) 0.055 (1.40) 0.049 (1.25) 0.150 (3.80) 0.139 (3.54) DIA. 0.055 (1.40) 0.047 (1.20) 0.343 (8.70) 0.114 (2.90) 0.067 (1.70) 0.331(8.40) TYP. 0.634 (16.10) 0.618 (15.70) PIN 0.118 (3.00) 0.102 (2.60) 0.523 (13.28) 0.507 (12.88) 0.035 (0.90) 0.064 (1.62) 0.056 (1.42) -0.200 (5.08) TYP.

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#### TO-262AA





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